

SAMTM Data Sheet SAM-1064-30-8ps-x, λ = 1064 nm

 $\begin{array}{ll} \text{Laser wavelength} & \lambda = 1064 \text{ nm} \\ \text{Absorbance} & A_0 = 30 \ \% \\ \text{Modulation depth} & \Delta R = 13 \ \% \\ \text{Non-saturable loss} & A_{\text{ns}} = 17 \ \% \\ \end{array}$

Saturation fluence $\Phi_{sat} = 97 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 8 \text{ ps}$

Damage threshold $\Phi = 2.5 \text{ mJ/cm}^2$

Chip area 4.0 x 4.0 other dimensions on request

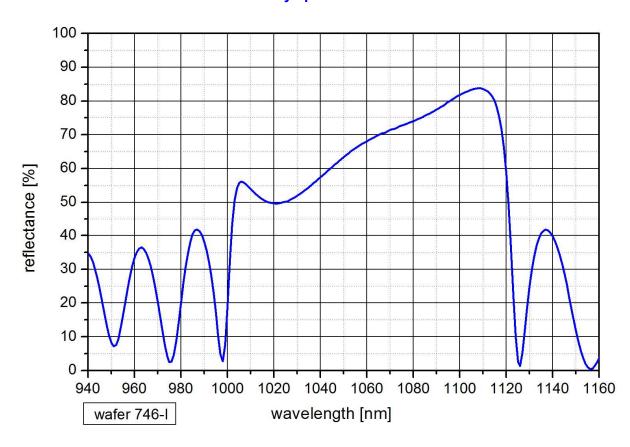
Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

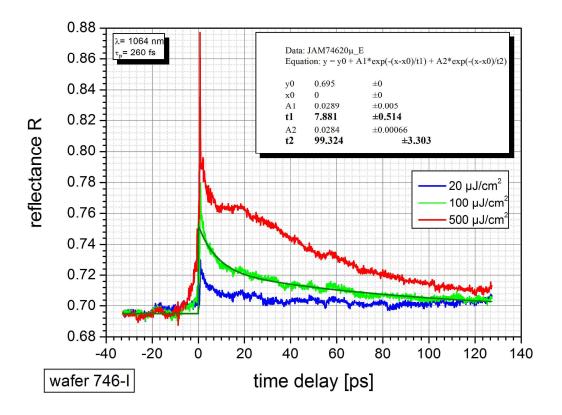
x = 0 unmounted
x = 12.7 g glued on a gold plated Cu-cylinder with 12.7 mm Ø
x = 25.4 g glued on a gold plated Cu-cylinder with 25.4 mm Ø
x = 12.7 s soldered on a gold plated Cu-cylinder with 12.7 mm Ø
x = 25.4 s soldered on a gold plated Cu-cylinder with 25.4 mm Ø
x = FC mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance





Pump-probe measurement



Saturation measurement

